

LOW DROP OR-ing POWER SCHOTTKY DIODE

MAIN PRODUCT CHARACTERISTICS

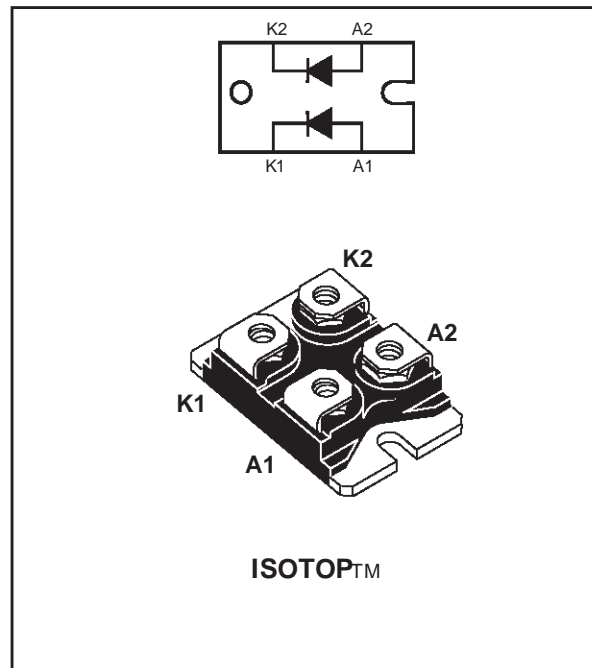
| | |
|-------------------|-----------------|
| $I_{F(AV)}$ | 2 x 60 A |
| V_{RRM} | 15 V |
| $T_j(\text{max})$ | 125 °C |
| $V_F(\text{max})$ | 0.31 V |

FEATURES AND BENEFITS

- VERY LOW DROP FORWARD VOLTAGE FOR LESS POWER DISSIPATION AND REDUCED HEATSINK
- INSULATED PACKAGE:
Insulated voltage = 2500 V_(RMS)
Capacitance = 45 pF

DESCRIPTION

Dual Schottky rectifier suited for Switched Mode Power Supplies and DC to DC power converters. Packaged in ISOTOP™, this device is especially intended for use as an OR-ing diode in fault tolerant power supply equipments.



ABSOLUTE RATINGS (limiting values, per diode)

| Symbol | Parameter | Value | Unit |
|--------------|--|--|------------------|
| V_{RRM} | Repetitive peak reverse voltage | 15 | V |
| $I_{F(RMS)}$ | RMS forward current | 160 | A |
| $I_{F(AV)}$ | Average forward current | $T_c = 115^\circ\text{C}$ $\delta = 1$ | A |
| I_{FSM} | Surge non repetitive forward current | $t_p = 10 \text{ ms}$ Sinusoidal | A |
| I_{RRM} | Repetitive peak reverse current | $t_p = 2 \mu\text{s}$ $F = 1 \text{ kHz}$ | A |
| T_{stg} | Storage temperature range | - 65 to + 150 | °C |
| T_j | Maximum operating junction temperature | 125 | °C |
| dV/dt | Critical rate of rise of reverse voltage | 10000 | V/ μs |

* : $\frac{dP_{tot}}{dT_j} < \frac{1}{R_{th(j-a)}}$ thermal runaway condition for a diode on its own heatsink

STPS120L15TV

THERMAL RESISTANCES

| Symbol | Parameter | | Value | Unit |
|---------------|------------------|-----------|-------|-----------------------------|
| $R_{th(j-c)}$ | Junction to case | Per diode | 0.45 | $^{\circ}\text{C}/\text{W}$ |
| | | Total | 0.28 | |
| $R_{th(c)}$ | | Coupling | 0.1 | |

STATIC ELECTRICAL CHARACTERISTICS (per diode)

| Symbol | Parameter | Tests conditions | | Min. | Typ. | Max. | Unit |
|---------|-------------------------|-----------------------------|--------------------|------|------|------|------|
| I_R^* | Reverse leakage current | $T_j = 100^{\circ}\text{C}$ | $V_R = 5\text{V}$ | | 450 | | mA |
| | | $T_j = 25^{\circ}\text{C}$ | $V_R = 12\text{V}$ | | | 22 | mA |
| | | $T_j = 100^{\circ}\text{C}$ | | | 0.7 | 2.2 | A |
| V_F^* | Forward voltage drop | $T_j = 25^{\circ}\text{C}$ | $I_F = 60\text{A}$ | | | 0.43 | V |
| | | $T_j = 125^{\circ}\text{C}$ | $I_F = 60\text{A}$ | | 0.27 | 0.31 | |

Pulse test : * $t_p = 380\ \mu\text{s}$, $\delta < 2\%$

To evaluate the conduction losses use the following equation :

$$P = 0.18 \times I_{F(AV)} + 2.2 \times 10^{-3} \times I_{F(RMS)}^2$$

Fig. 1: Average forward power dissipation versus average forward current (per diode).

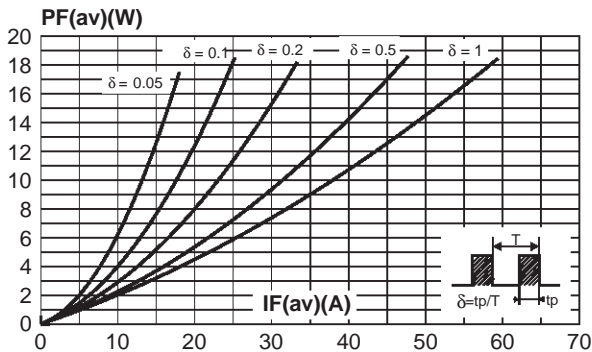


Fig. 2: Average forward current versus ambient temperature ($\delta = 1$) (per diode).

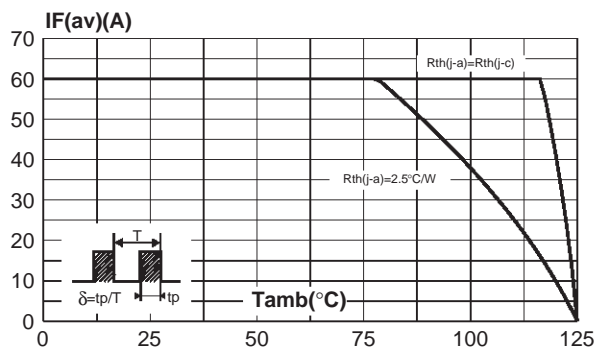


Fig. 3: Non repetitive surge peak forward current versus overload duration (maximum values per diode).

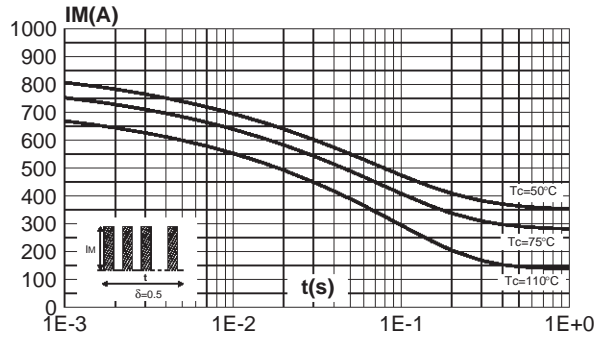


Fig. 4: Relative variation of thermal impedance junction to case versus pulse duration.

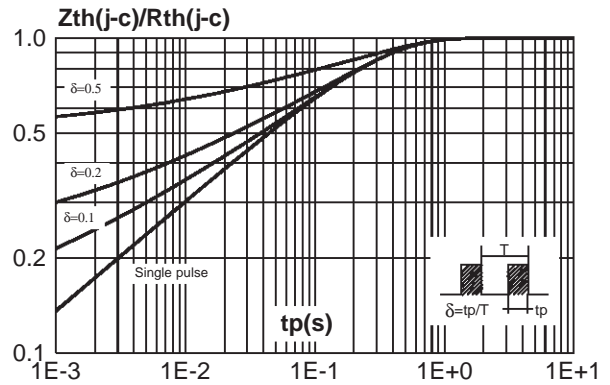


Fig. 5: Reverse leakage current versus reverse voltage applied (typical values per diode).

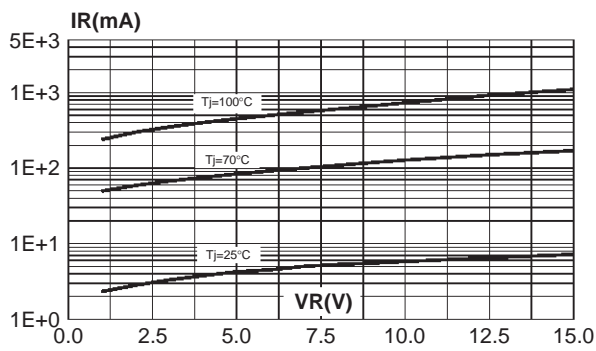


Fig. 6: Junction capacitance versus reverse voltage applied (typical values per diode).

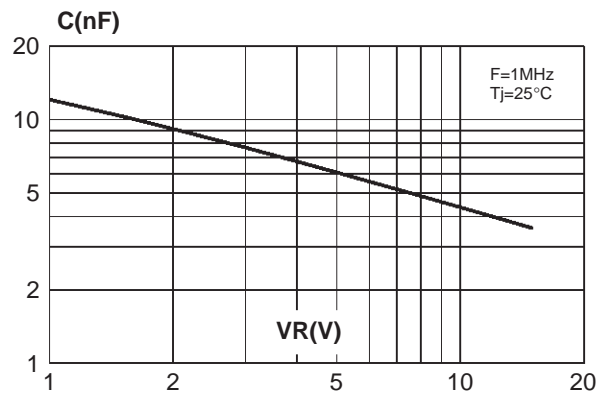
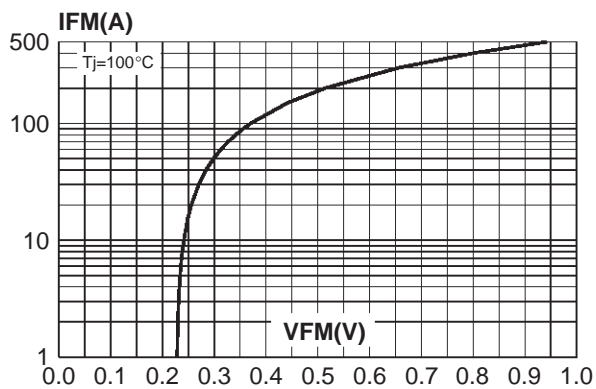


Fig. 7: Forward voltage drop versus forward current (maximum values per diode).



STPS120L15TV

PACKAGE MECHANICAL DATA ISOTOP

| REF. | DIMENSIONS | | | |
|------|-------------|-------|------------|-------|
| | Millimeters | | Inches | |
| | Min. | Max. | Min. | Max. |
| A | 11.80 | 12.20 | 0.465 | 0.480 |
| A1 | 8.90 | 9.10 | 0.350 | 0.358 |
| B | 7.8 | 8.20 | 0.307 | 0.323 |
| C | 0.75 | 0.85 | 0.030 | 0.033 |
| C2 | 1.95 | 2.05 | 0.077 | 0.081 |
| D | 37.80 | 38.20 | 1.488 | 1.504 |
| D1 | 31.50 | 31.70 | 1.240 | 1.248 |
| E | 25.15 | 25.50 | 0.990 | 1.004 |
| E1 | 23.85 | 24.15 | 0.939 | 0.951 |
| E2 | 24.80 typ. | | 0.976 typ. | |
| G | 14.90 | 15.10 | 0.587 | 0.594 |
| G1 | 12.60 | 12.80 | 0.496 | 0.504 |
| G2 | 3.50 | 4.30 | 0.138 | 0.169 |
| F | 4.10 | 4.30 | 0.161 | 0.169 |
| F1 | 4.60 | 5.00 | 0.181 | 0.197 |
| P | 4.00 | 4.30 | 0.157 | 0.69 |
| P1 | 4.00 | 4.40 | 0.157 | 0.173 |
| S | 30.10 | 30.30 | 1.185 | 1.193 |

| Ordering type | Marking | Package | Weight | Base qty | Delivery mode |
|---------------|--------------|---------|-------------------------|----------|---------------|
| STPS120L15TV | STPS120L15TV | ISOTOP | 28g (without screws) | 10 | Tube |

- Cooling method: by conduction (C)
- Recommended torque value : 1.3 N.m.
- Maximum torque value: 1.5 N.m.
- Epoxy meets UL94,V0

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